PI3B16209
PI3B162209 (25Ω)

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3.3V, 18-Bit Bus Exchange Switch

Product Features

- Near-zero propagation delay
- 5Ω switches connect inputs to outputs
- Fast Switching speed - 5ns (max.)
- Operating Range: 3.0V to 3.6V
- Industrial operating temperature: –40°C to +85°C
- Packages available:
  – 48-pin 240-mil wide thin plastic TSSOP (A)
 – 48-pin 300-mil wide plastic SSOP (V)

Product Description

Pericom Semiconductor's PI3B series of logic circuits are produced in the Company's advanced 0.35 micron CMOS technology.

The PI3B16209 and PI3B162209 are 3.3 volt, 18-bit bus exchange switches designed with a low ON resistance (5Ω) allowing inputs to be connected directly to outputs. The devices operate as an 18-bit bus switch or as a 9-bit exchanger, providing data exchange between the four signal ports via the data select pins (S0-S2).

The PI5C162209 device has a built-in 25-ohm series resistor to reduce noise resulting from reflections, thus eliminating the need for an external terminating resistor.

Logic Block Diagram
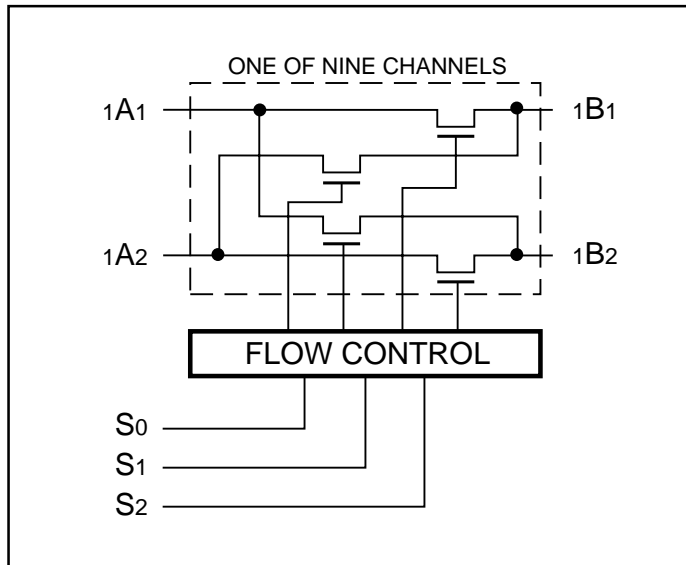
Product Pin Configuration
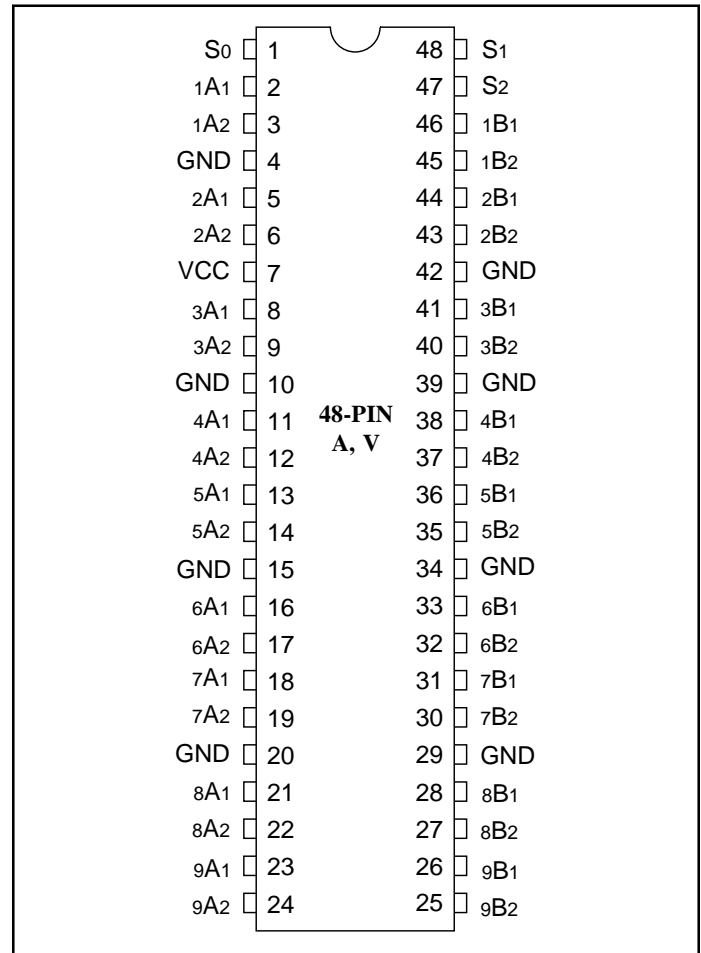
Truth Table

Function	S2	S1	S0	A1	A2
Disconnect	L	L	L	Z	Z
A1 to B1	L	L	H	B1	Z
A1 to B2	L	H	L	B2	Z
A2 to B1	L	H	H	Z	B1
A2 to B2	H	L	L	Z	B2
Disconnect	H	L	H	Z	Z
A1 to B1, A2 to B2	H	H	L	B1	B2
A1 to B2, A2 to B1	H	H	H	B2	B1

Note:

1. H = High Voltage Level
   L = Low Voltage Level
   Z = High Impedance

Product Pin Description

Pin Name	I/O	Description
S0-S2	I	Select Inputs
xAx	I/O	Bus A
xBx	I/O	Bus B

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–0°C to +85°C
Supply Voltage Range	–0.5V to +4.6V
DC Input Voltage	–0.5V to +4.6V
DC Output Current	120 mA
Power Dissipation	0.5W

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, T_A = –40°C to +85°C, V_{CC} = 3.0V to 3.6V)

Parameters	Description	Test Conditions[1]		Min.	Typ[2]	Max.	Units
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level		–0.5	—	0.8	V
I_{IH}	Input HIGH Current	V_{CC} = Max., V_{IN} = V_{CC}		—	—	±1	µA
I_{IL}	Input LOW Current	V_{CC} = Max., V_{IN} = GND		—	—	±1	µA
I_{OZH}	High Impedance Output Current	$0 \leq A, B \leq V_{CC}$		—	—	±1	µA
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = –18mA		—	-0.7	–1.2	V
R_{ON}	Switch On Resistance[3]	V_{CC} = Min., V_{IN} = 0.0V, I_{ON} = 48mA	16209	—	5	8	Ω
			162209	20	28	40	
		V_{CC} = Min., V_{IN} = 2.4V, I_{ON} = 15mA	16209	—	10	15	Ω
			162209	20	35	48	

Capacitance (T_A = 25°C, f = 1 MHz)

Parameters[4]	Description	Test Conditions	Typ	Units
C_{IN}	Input Capacitance	V_{IN} = 0V	3	pF
C_{OFF}	A/B Capacitance, Switch Off	V_{IN} = 0V	14	pF
C_{ON}	A/B Capacitance, Switch On	V_{IN} = 0V	30	pF

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 3.3V, T_A = 25°C ambient and maximum loading.
3. Measured by the voltage drop between A and B pin at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A,B) pins.
4. This parameter is determined by device characterization but is not production tested.

Power Supply Characteristics

Parameters	Description	Test Conditions[1]		Min.	Typ[2]	Max.	Units
I_{CC}	Quiescent Power Supply Current	V_{CC} = Max.	V_{IN} = GND or V_{CC}			10	μA
ΔI_{CC}	Supply Current per Input @ TTL HIGH	V_{CC} = Max.	V_{IN} = 3.0V[3]			750	μA
I_{CCD}	Supply Current per Input per MHz[4]	V_{CC} = Max. A and B Pins Open $\overline{BE}$ = GND Control Input Toggling 50% Duty Cycle				0.25	mA/ MHz

Notes:
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at Vcc = 3.3V, +25°C ambient.
3. Per TTL driven input (control input only); A and B pins do not contribute to I_{CC}.
4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

Switching Characteristics over Operating Range

Parameters	Description	Conditions[1]		Com.		Units
				Min.	Max.	
t_{PLH}	Propagation Delay[2,3]	Cl = 50pF	16209		0.25	
t_{PHL}	Ax to Bx, Bx to Ax	Rl = 500Ω	162209		1.25	
t_{PZH}	Bus Enable Time	Cl = 50pF, R_L= 500Ω,		1	4.5	ns
t_{PZL}	$\overline{BE}$ to Ax or Bx	R = 500Ω				
t_{PHZ}	Bus Disable Time			1	5	
t_{PLZ}	$\overline{BE}$ to Ax or Bx					

Notes:
1. See test circuit and waveforms.
2. This parameter is guaranteed but not tested on Propagation Delays.
3. The bus switch contributes no propagational delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.